TOPTICA EAGLEYARD

EYP-RWE-0655-00505-2000-SOT02-0000

Revision 1.00

GAIN CHIPS AR coated Fabry-Perot Laser



General Product Information

| Product | Application |
|--|--------------|
| tunable 655 nm Fabry-Perot Laser | Spectroscopy |
| for use in an External Cavity Diode Laser (ECDL) | |
| sealed SOT Housing | |
| Monitor Diode | |



Absolute Maximum Ratings

| Parameter | Symbol | Unit | min | typ | max |
|---------------------------------|------------------|------|-----|-----|-----|
| Storage Temperature | T _S | °C | -40 | | 85 |
| Operational Temperature at Case | T_{C} | °C | 0 | | 20 |
| Forward Current | I _F | mA | | | 160 |
| Reverse Voltage | V_R | V | | | 0 |
| Output Power (extracavity) | P_{opt} | mW | | | 30 |

Measurement Conditions / Comments

Stess in excess of the Absolute Maximum Ratings can cause permanent damage to the device.

Recommended Operational Conditions

| Parameter | Symbol | Unit | min | typ | max |
|---------------------------------|----------------|------|-----|-----|-----|
| Operational Temperature at Case | T _C | °C | | | 20 |
| Forward Current | I_{F} | mA | | | 160 |

Characteristics at T_C= at 20°C, BOL

under recommended working condition, with external cavity

| Parameter | Symbol | Unit | min | typ | max |
|----------------------------|------------------------|------|-----|-------|-----|
| Center Wavelength | λ_{C} | nm | | 655 | |
| Tuning Range | $\Delta \lambda_{tun}$ | nm | 650 | | 660 |
| Output Power | P _{opt} | mW | | 20 | |
| Polarization | | | | TE | |
| Spatial Mode (transversal) | | | | TEM00 | |
| | | | | | |

Measurement Conditions / Comments

The actual achieved wavelength and power are strongly influenced by the external cavity. eyP gives no guarantee on these parameters.

E field parallel to Pin 2 - Pin 3 - plane Fundamental Mode



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Amplified Spontaneous Emission (ASE) without external cavity

| Parameter | Symbol | Unit | min | typ | max |
|-------------------------------|-----------------------|-------|-----|-----|-----|
| Monitor Detector Responsivity | I_{mon} / P_{ASE} | μA/mW | 1 | | 40 |

| Measurement Conditions / Comments |
|-----------------------------------|
| $U_{R MD} = 5 V$ |

Chip Parameter

| Parameter | Symbol | Unit | min | typ | max |
|-----------------------------|----------|------|-----|--------------------|--------------------|
| Cavity Length | L | μm | | 2000 | |
| Reflectivity at Front Facet | R_{ff} | | | 3·10 ⁻⁴ | 1·10 ⁻³ |

| Measurement Conditions / Comments |
|-----------------------------------|
| |
| |



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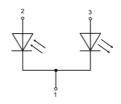
Package Dimensions

| Parameter | Symbol | Unit | min | typ | max |
|---------------------------------|-----------|------|------|------|------|
| Height of Emission Plane | h | mm | 3.50 | 3.65 | 3.70 |
| Excentricity of Emission Center | R | mm | | | 0.12 |
| Pin Length | L_{PIN} | mm | | 14 | |

Measurement Conditions / Comments
reference plane: top side of TO header
reference: center of outer diameter of header

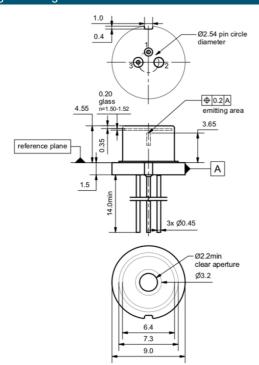
Package Pinout

- 1 Laser Diode Cathode, Monitor Diode Cathode, Case
- 2 Photo Diode Anode
- 3 Laser Diode Anode





Package Drawings





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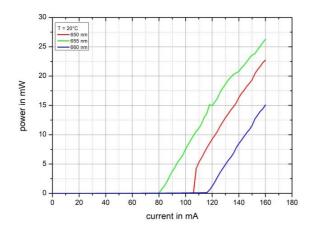


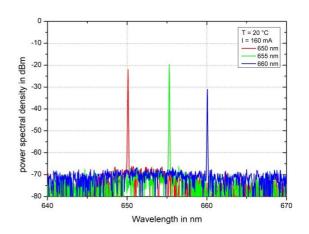
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Typical Measurement Results

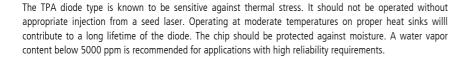




Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.



The laser emission from this diode is close to the invisible infrared region of the electromagnetic spectrum. Avoid direct and/or indirect exposure to the free running beam. Collimating the free running beam with optics as common in optical instruments will increase threat to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.











